

TRENCHSTOP™ Series

Low Loss IGBT : IGBT in TRENCHSTOP[™] and Fieldstop technology



Features:

- Very low V_{CE(sat)} 1.5V (typ.) .
- Maximum Junction Temperature 175°C
- Short circuit withstand time 5µs ٠
- Designed for : •
 - Frequency Converters
 - Uninterrupted Power Supply
 - TRENCHSTOP™ and Fieldstop technology for 600V applications offers :
 - very tight parameter distribution
 - high ruggedness, temperature stable behavior
 - very high switching speed
- Positive temperature coefficient in $V_{CE(sat)}$.
- Low EMI
- Pb-free lead plating; RoHS compliant ٠
- Qualified according to JEDEC¹ for target applications
- Complete product spectrum and PSpice Models : http://www.infineon.com/igbt/

Туре	V _{CE}	I _C	V _{CE(sat), Tj=25℃}	T _{j,max}	Marking Code	Package
IGP15N60T	600V	15A	1.5V	175°C	G15T60	PG-TO220-3

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage, $T_j \ge 25^{\circ}C$	V _{CE}	600	V
DC collector current, limited by <i>T</i> _{jmax}			
$T_{\rm C}$ = 25°C, value limited by bondwire	I _C	26	
$T_{\rm C} = 100^{\circ}{\rm C}$		23	A
Pulsed collector current, t_p limited by T_{jmax}	I _{Cpuls}	45	
Turn off safe operating area, $V_{CE} = 600V$, $T_j = 175^{\circ}C$, $t_p = 1\mu s$	-	45	
Gate-emitter voltage	V _{GE}	±20	V
Short circuit withstand time ²⁾	4	5	
V_{GE} = 15V, $V_{\text{CC}} \le 400$ V, $T_j \le 150^\circ$ C	tsc	5	μS
Power dissipation $T_{\rm C} = 25^{\circ}{\rm C}$	P _{tot}	130	W
Operating junction temperature	Tj	-40+175	
Storage temperature	T _{stg}	-55+150	_∘c
Soldering temperature wavesoldering, 1.6 mm (0.063 in.) from case for 10s		260	

¹ J-STD-020 and JESD-022 ²⁾ Allowed number of short circuits: <1000; time between short circuits: >1s.



C C C C	
PG-TO220-3	



TRENCHSTOP[™] Series

Thermal Resistance

Parameter	Symbol	Conditions	Max. Value	Unit
Characteristic				
IGBT thermal resistance, junction – case	R _{thJC}		1.15	K/W
Thermal resistance, junction – ambient	R _{thJA}		62	

Electrical Characteristic, at $T_j = 25$ °C, unless otherwise specified

Parametar	Symbol	Conditiono	Value			11
Parameter	Symbol	Conditions	min.	Тур.	max.	Unit
Static Characteristic						
Collector-emitter breakdown voltage	$V_{(BR)CES}$	$V_{GE}=0V, I_{C}=0.2mA$	600	-	-	V
Collector-emitter saturation voltage	V _{CE(sat)}	$V_{\rm GE} = 15 \rm V, \ I_{\rm C} = 15 \rm A$				
		<i>T</i> _j =25°C	-	1.5	2.05	
		<i>T</i> _j =175°C	-	1.9	-	
Gate-emitter threshold voltage	V _{GE(th)}	$I_{\rm C} = 210 \mu {\rm A}, V_{\rm CE} = V_{\rm GE}$	4.1	4.9	5.7	
Zero gate voltage collector current	I _{CES}	V _{CE} =600V, V _{GE} =0V				μA
		<i>T</i> _j =25°C	-	-	40	
		<i>T</i> _j =175°C	-	-	1000	
Gate-emitter leakage current	I _{GES}	$V_{\rm CE} = 0 \rm V, V_{\rm GE} = 20 \rm V$	-	-	100	nA
Transconductance	$g_{ m fs}$	$V_{\rm CE} = 20 V, I_{\rm C} = 15 A$	-	8.7	-	S
Integrated gate resistor	R _{Gint}			-		Ω

Dynamic Characteristic

Input capacitance	Ciss	V _{CE} =25V,	-	860	-	pF
Output capacitance	Coss	$V_{\rm GE}=0V$,	-	55	-	
Reverse transfer capacitance	Crss	f=1MHz	-	24	-	
Gate charge	Q _{Gate}	$V_{\rm CC} = 480 \text{V}, \ I_{\rm C} = 15 \text{A}$	-	87	-	nC
		$V_{GE}=15V$				
Internal emitter inductance	LE		-	7	-	nH
measured 5mm (0.197 in.) from case						
Short circuit collector current ¹⁾	I _{C(SC)}	$V_{GE} = 15V, t_{SC} \le 5\mu s$ $V_{CC} = 400V,$ $T_j = 150^{\circ}C$	-	137.5	-	A

¹⁾ Allowed number of short circuits: <1000; time between short circuits: >1s.



TRENCHSTOP[™] Series

Switching Characteristic, Inductive Load, at Tj=25 °C

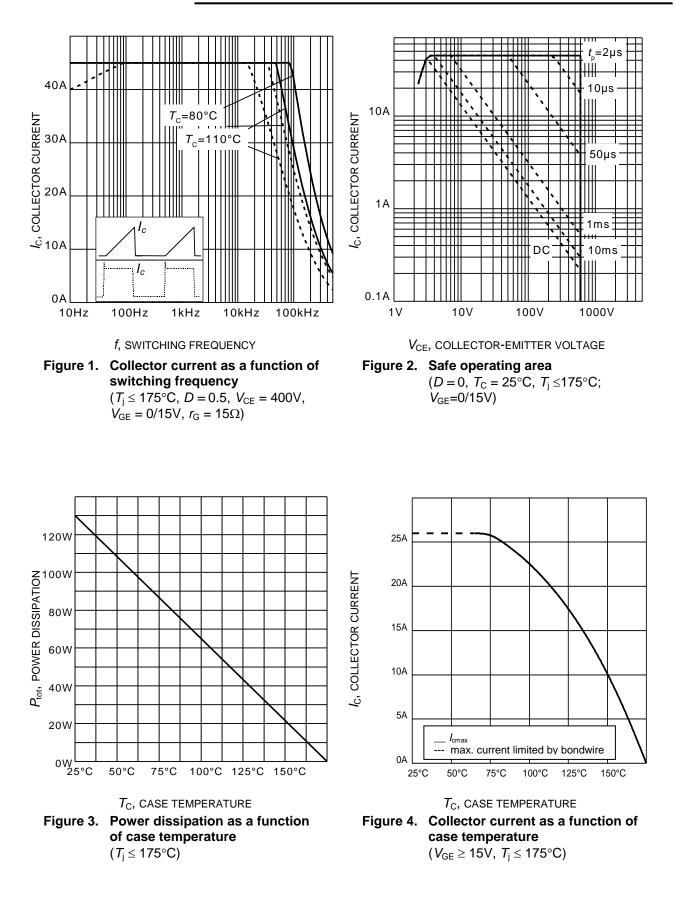
Parameter	Symbol	Q an dition a	Value			11
		Conditions	min.	Тур.	max.	Unit
IGBT Characteristic						
Turn-on delay time	t _{d(on)}	<i>T</i> _j =25°C,	-	17	-	ns
Rise time	t _r	$V_{CC}=400V, I_{C}=15A,$ $V_{GE}=0/15V, r_{G}=15\Omega,$ $L_{\sigma}=154nH, C_{\sigma}=39pF$ L_{σ}, C_{σ} from Fig. E Energy losses include "tail" and diode reverse	-	11	-	
Turn-off delay time	$t_{d(off)}$		-	188	-	
Fall time	t _f		-	50	-	
Turn-on energy	Eon		-	0.22	-	mJ
Turn-off energy	E _{off}		-	0.35	-	
Total switching energy	Ets	recovery.	-	0.57	-	1

Switching Characteristic, Inductive Load, at T_j =175 °C

Parameter	Symbol	Conditions	Value			11
			min.	Тур.	max.	Unit
IGBT Characteristic						-
Turn-on delay time	t _{d(on)}	<i>T</i> _j =175°C,	-	17	-	ns
Rise time	t _r	$V_{CC}=400V, I_{C}=15A,$ $V_{GE}=0/15V, r_{G}=15\Omega,$ $L_{\sigma}=154nH, C_{\sigma}=39pF$ L_{σ}, C_{σ} from Fig. E Energy losses include "tail" and diode reverse recovery.	-	15	-]
Turn-off delay time	$t_{d(off)}$		-	212	-	
Fall time	t _f		-	79	-	
Turn-on energy	Eon		-	0.34	-	mJ
Turn-off energy	E _{off}		-	0.47	-	7
Total switching energy	Ets		-	0.81	-	1

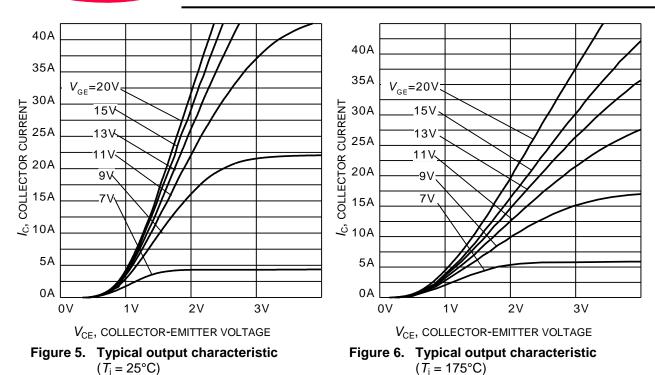


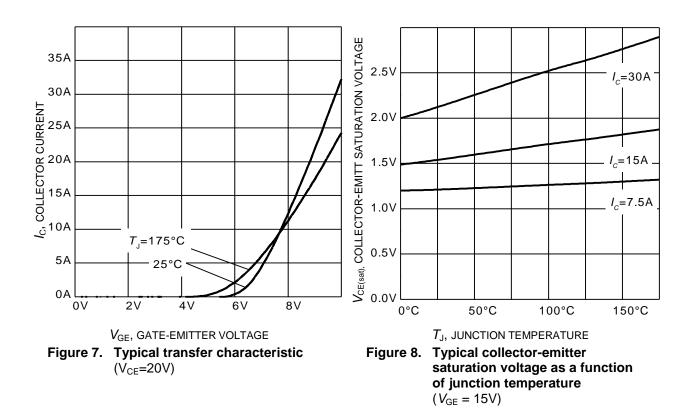
TRENCHSTOP[™] Series





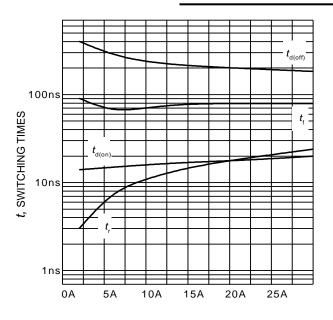
TRENCHSTOP™ Series





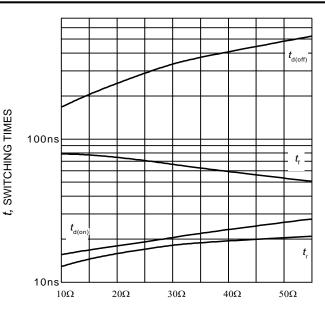


TRENCHSTOP™ Series

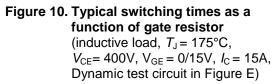


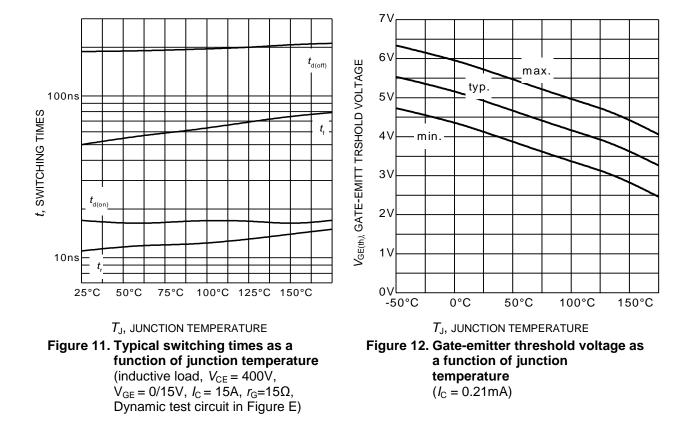
 I_C , COLLECTOR CURRENT

Figure 9. Typical switching times as a function of collector current (inductive load, $T_J=175^{\circ}C$, $V_{CE} = 400V$, $V_{GE} = 0/15V$, $r_G = 15\Omega$, Dynamic test circuit in Figure E)



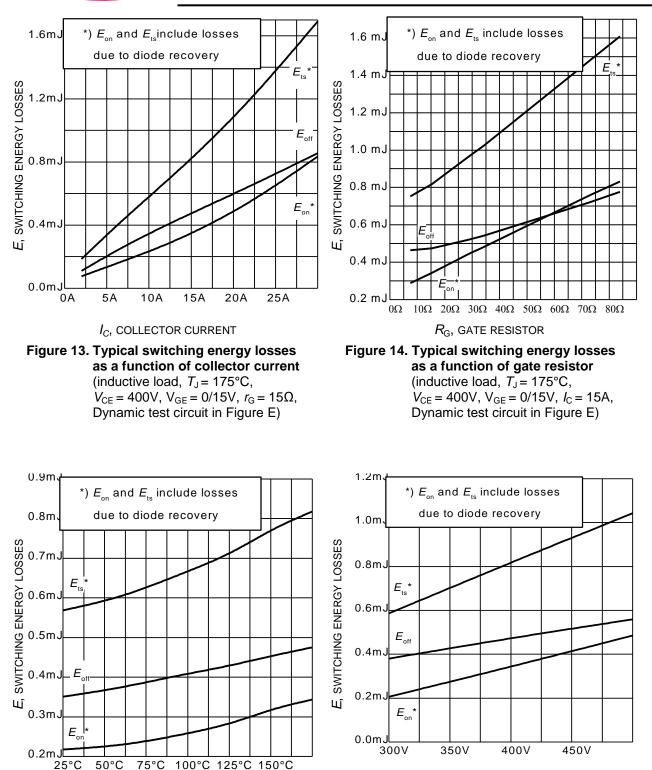








TRENCHSTOP™ Series



 V_{CE} , COLLECTOR-EMITTER VOLTAGE Figure 16. Typical switching energy losses as a function of collector emitter

> **voltage** (inductive load, $T_J = 175^{\circ}C$, $V_{GE} = 0/15V$, $I_C = 15A$, $r_G = 15\Omega$, Dynamic test circuit in Figure E)

 $T_{\rm J}$, JUNCTION TEMPERATURE

as a function of junction

(inductive load, $V_{CE} = 400V$,

 $V_{GE} = 0/15V, I_C = 15A, r_G = 15\Omega,$

Dynamic test circuit in Figure E)

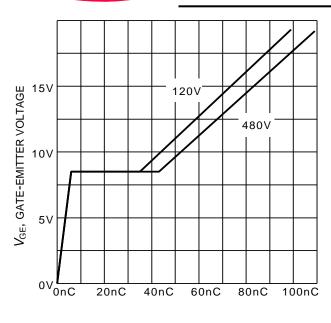
Figure 15. Typical switching energy losses

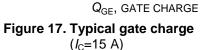
temperature





TRENCHSTOP™ Series





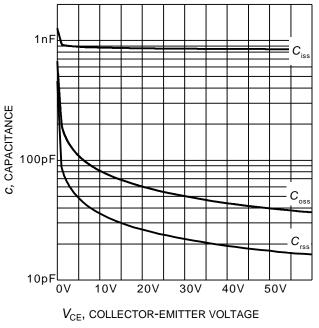
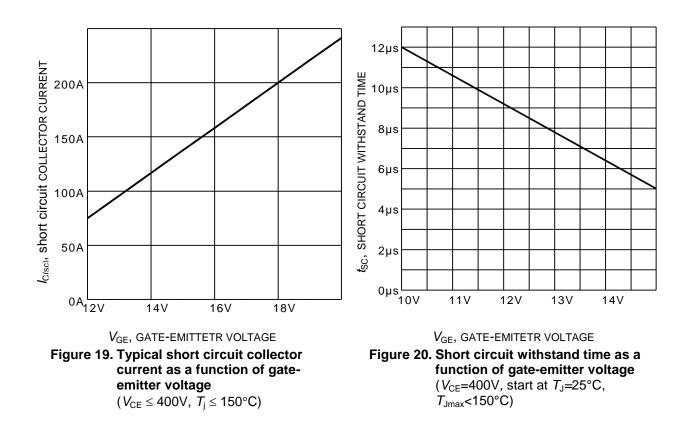
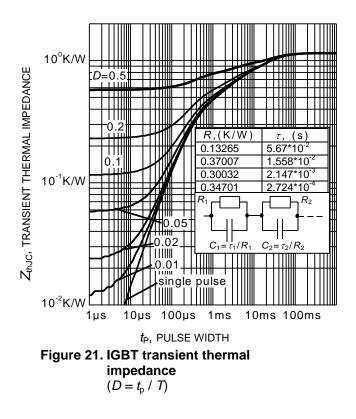


Figure 18. Typical capacitance as a function of collector-emitter voltage $(V_{GE}=0V, f = 1 \text{ MHz})$





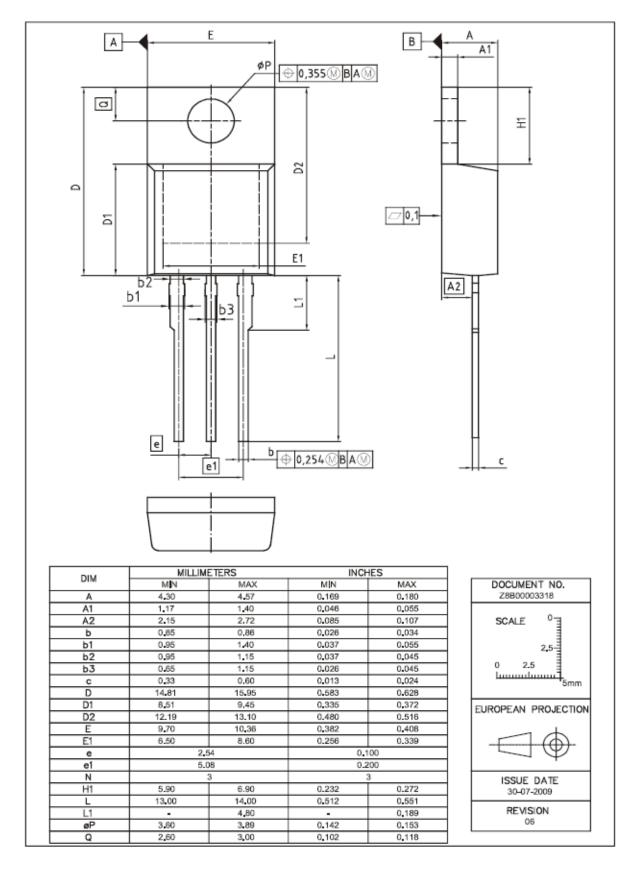
TRENCHSTOP™ Series





TRENCHSTOP™ Series

PG-TO220-3





TRENCHSTOP[™] Series

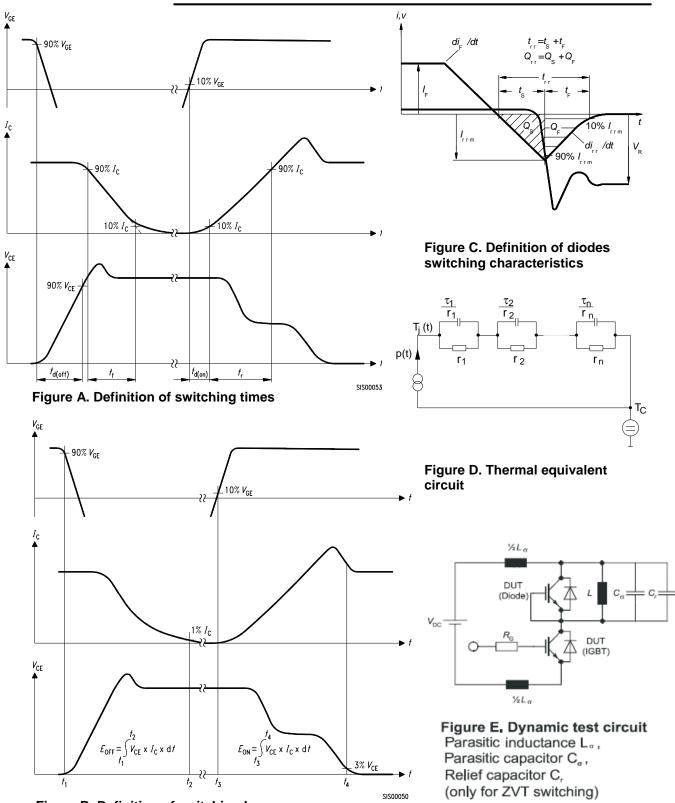


Figure B. Definition of switching losses



Published by Infineon Technologies AG 81726 Munich, Germany © 2015 Infineon Technologies AG All Rights Reserved.

Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

The Infineon Technologies component described in this Data Sheet may be used in life-support devices or systems and/or automotive, aviation and aerospace applications or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support, automotive, aviation and aerospace device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for IGBT Transistors category:

Click to view products by Infineon manufacturer:

Other Similar products are found below :

748152A APT20GT60BRDQ1G APT50GT60BRG NGTB10N60FG STGFW20V60DF APT30GP60BG APT45GR65B2DU30 GT50JR22(STA1ES) TIG058E8-TL-H IGW40N120H3FKSA1 VS-CPV364M4KPBF NGTB25N120FL2WAG NGTG40N120FL2WG RJH60F3DPQ-A0#T0 APT40GR120B2SCD10 APT15GT120BRG APT20GT60BRG NGTB75N65FL2WAG NGTG15N120FL2WG IXA30RG1200DHGLB IXA40RG1200DHGLB APT70GR65B2DU40 NTE3320 QP12W05S-37A IHFW40N65R5SXKSA1 APT70GR120J APT35GP120JDQ2 XD15H120CX1 XD25H120CX0 XP15PJS120CL1B1 IGW30N60H3FKSA1 STGWA8M120DF3 IGW08T120FKSA1 IGW75N60H3FKSA1 FGH60N60SMD_F085 FGH75T65UPD STGWA15H120F2 IKA10N60TXKSA1 IHW20N120R5XKSA1 RJH60D2DPP-M0#T2 IKP20N60TXKSA1 IHW20N65R5XKSA1 APT70GR120JD60 AOD5B60D APT70GR120L STGWT60H65FB STGWT60H65DFB STGWT40V60DF STGWT20V60DF STGB10NB37LZT4